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Graphene Oxide: A Comparison of Reduction Methods

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Abstract: This paper presents a comparison of traditional thermal and chemical reduction methods with more recent ionizing radiation reduction via gamma rays and electron beams (e-beams). For GO, all synthesis protocols were adapted to increase production scale and are a contribution of this work. The typical Raman D-band of the GO was prominent (I_D/I_G ratio increased sixfold). When comparing the GO reduction techniques, dramatic differences in efficiency and GO particle characteristics were observed. Although thermal and chemical reduction are effective reduction methods, as shown through the use of FTIR spectroscopy and the C/O ratio from EDS chemical analysis, the thermal process renders great weight losses, whereas chemical processing may involve the use of hazardous chemical compounds. On the other hand, comparing the gamma rays and e-beam for 80 kGy, the Raman spectra and chemical analysis suggested that the e-beam caused a greater GO reduction: C/O ratio from EDS of 5.4 and 4.1, respectively. In addition to being fast and effective, ionizing radiation reduction processes allow easier control of the reduction degree by adjusting the radiation dose. When the dose increased from 40 to 80 kGy, the Raman spectra and EDS showed that the I_D/I_G and C/O ratios increased by 15 and 116%, respectively.

Keywords: graphene oxide; Hummers method; reduced graphene oxide; chemical reduction; green reduction; electron beam reduction; thermal reduction; radiation reduction; gamma ray reduction



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1. Introduction

In recent decades, 2D materials have attracted a lot of attention in materials engineering because of their high thermal conductivity, optical transparency and high surface area. Among the different 2D materials, metal dichalcogenides [1], boron nitride [2], carbon nitride [3], MXenes [4], and graphene stand out [5,6].

Graphene is a one-atom-thick layer composed of hexagonally bonded carbons in sp^2 hybridization [7]. Graphene can be produced from graphite via chemical vapor deposition (CVD) [8], mechanical [9], chemical [10] or electrochemical [11–13] methods. After the first graphene sheet was synthesized via mechanical exfoliation, many researchers became interested in studying this material due to its electrical and thermal conductivity and gas barrier properties as well as the high Young's modulus [5,14].

However, to produce graphene in large quantities, the graphite oxidation process is preferable to produce graphite oxide, followed by exfoliation to graphene oxide (GO) and reduction to obtain reduced graphene oxide (rGO) [15]. GO can be produced via different methodologies. It was first described by Brodie (1859), who applied fuming HNO_3 (nitric acid) and $KClO_3$ (potassium chlorate) as intercalant and oxidant agents, respectively [16]. The complexity of this method and its hazardous process led to the need to create new

methodologies for GO production. Hummers (1958) developed a protocol where H_2SO_4 (sulfuric acid), NaNO_3 (sodium nitrate) and KMnO_4 (potassium permanganate) were used to oxidize graphite [17]. The benefit of the latter method was the removal of HNO_3 via the addition of KMnO_4 as an oxidizing agent. Nevertheless, some improvements were needed, such as an increase in the oxidation level to mitigate the number of unoxidized graphite particles in the produced material [18–21]. Consequently, several modifications have been made to the Hummers method, originating the modified Hummers method [22]. Hou et al. demonstrated that increasing the amount of H_2SO_4 and KMnO_4 increased the oxidation degree [23]. Aixart et al. found that the degree of exfoliation increased proportionally with the reaction time [24]. Ucar et al. verified that applying a pre-oxidation step before the modified Hummers method could increase the oxygen content on the graphene oxide sheets [25].

The majority of publications utilized a graphite content ranging from 0.5 to 3 g per batch of GO production, which may not be representative of studies aimed at producing GO in large scale [23,26–30].

During the process of graphite oxidation using the Hummers method, sp^2 bonds are interrupted due to the insertion of oxygen-containing groups (hydroxy, epoxy, carbonyls, carboxyl, ketones, alcohols, and lactones) on their basal planes and edges, which significantly alter the van der Waals interactions between the layers and endow GO with strong hydrophilicity. Some GO properties are impacted by the conversion to an sp^3 structure, such as the decrease in electrical and thermal conductivities when compared to the ones of pristine graphene [31,32].

With the purpose of restoring the intrinsic properties of graphene, GO can be converted into reduced graphene oxide (rGO) via the removal of oxygen-containing groups. There are numerous methodologies to reduce graphene oxide. Thermal and chemical reductions are the procedures with the highest number of publications [33,34]. Feng et al. reviewed the latest developments of different strategies to reduce GO, and they concluded that the precise oxidation of GO via a reliable technique was still questionable and, consequently, it was very difficult to control the degree of reduction precisely and repeatedly [35].

There is a growing interest in reducing GO using thermal energy to obtain rGO with structural and electrical properties similar to the ones of graphene sheets [36]. It has been reported that between 140 and 180 °C, the vaporization process of intercalated water molecules dominates, whereas, for the range of temperatures between 180 and 600 °C, the main carboxyl groups are removed. In the temperature range of 600–800 °C, all the residual carboxyl and partial hydroxyl groups are released. A further increase in the temperature to around 1000 °C causes the removal of the residual hydroxyl and partial epoxide groups leading to the generation of a large number of structural defects caused by C=C cracking [37]. Sieradzka et al. studied the effects of graphite particle size on the morphological structure of thermally reduced rGO and clearly showed that such morphologies affected the electrical properties of reduced graphene oxides [38].

Another well-known method is chemical reduction because of its large-scale reduction potential [35,39]. Hydrazine monohydrate ($\text{N}_2\text{H}_4 \cdot \text{H}_2\text{O}$) is the most used chemical reducing agent despite the fact that it is a very toxic chemical component. Furthermore, the N_2H_4 reduction process incorporates C-N groups into the graphene sheet. Sodium borohydride (NaBH_4) is an alternative to reduce graphene oxide via chemical reduction despite the fact that it is also toxic. Despite the potential for large-scale production, other papers showed that the initial amounts of GO to produce rGO are still low, up to 0.5 g [37,40,41]. A more recent method that has been attracting the attention of researchers is the electrochemical method, which shows potential for large-scale production, being both green and sustainable and allowing for the oxidation and defect control of the rGO produced [11–13]. The reduction of graphene oxide via ionizing radiation has also been recently studied [19,42,43]. This technique consists of reducing the GO by submitting its particles to gamma radiation or to an electron beam (e-beam) [44]. The principle of this method is to create active free radicals with reduction potential (product of radiolysis) to chemically react with GO,

therefore reducing it. When a suspension of GO in water/alcohol is submitted to radiation, the water molecules will decompose into oxidizing and reducing species: hydroxyl radical ($\bullet\text{OH}$), hydrogen radical ($\bullet\text{H}$), and hydrated electrons (e_{aq-}). The presence of alcohol in the dispersion decreases the concentration of oxidative species ($\bullet\text{OH}$), creating a high-capacity reducing solution, which reduces the GO particles [42–46]. The goal is to produce rGO faster, more efficiently, and that is also easily scalable [47,48].

There are few studies reported in the literature about the electron beam reduction method. An advantage of this technique is the possibility of reducing GO without the use of toxic agents. Yang et al. studied several radiation doses: 5, 15, 20, and 40 kGy. They could not obtain rGO with these levels, but they found that the interplanar spacing decreased, indicating the removal of some oxide groups from GO [47]. On the other hand, Jung et al. applied the radiation dose of 50, 100, and 200 kGy and showed that the electrical conductivity increased proportionally with the radiation dose [48].

Regarding the gamma radiation method, it is a less recent methodology than the e-beam method. It uses radioactive isotopes as the energy source. It was applied by Atta et al. to reduce GO with 100 kGy [49]. Jacovone et al. reduced GO with radiation doses of 20, 40, and 80 kGy [50]. Ansón-Casaos et al. applied radiation doses of 60, 90, and 150 kGy [51]. Although these studies have explored the GO reduction by ionizing radiation, the lack of complete characterizations of the reduced materials has not allowed a conclusive comparison of the effects of several radiation doses.

In this context, the objective of this work was to produce GO using a scalable method and with an appropriate degree of oxidation and submit it to four different reduction methods, comparing the traditional GO thermal and chemical reduction methods with the more recent ionizing radiation reduction using gamma rays and e-beam. Characterizations of the GO and rGO were performed using Raman, XRD, SEM, EDS, and AFM techniques. Among the numerous articles reporting studies on these techniques, to our knowledge, few use different reduction processes starting from the same GO and provide an appropriate characterization of the rGO produced. All production protocols, from graphite to graphene oxide, were adapted to increase production scale and are a contribution of this work. Therefore, to increase the amount of initial graphite and ensure its proper oxidation, four main adjustments were performed on the original method described by Hummers [17]: (1) addition of the pre-oxidation step, (2) increasing the dosage of H_2SO_4 , (3) increasing the reaction time, and (4) inclusion of the centrifugation process to remove unoxidized particles of graphite from the obtained material.

2. Materials and Methods

The graphite specified as Grafmax FP 120, with a carbon content of 99.98%, was supplied by the National Graphite company (São Paulo, Brazil). For GO and rGO productions, the following chemical compounds (reagent grade) were used: sulfuric acid (H_2SO_4), potassium persulfate ($\text{K}_2\text{S}_2\text{O}_8$), diphosphorus pentoxide (P_2O_5), sodium nitrate (NaNO_3), potassium permanganate (KMnO_4), hydrogen peroxide (H_2O_2), hydrochloric acid (HCl), sodium borohydride (NaBH_4), and ethyl alcohol 99.5% ($\text{C}_2\text{H}_6\text{O}$). Chemical reagents were purchased from Synth (Diadema, Brazil) and Sigma-Aldrich Brasil (São Paulo, Brazil).

In this work, the synthesis of GO was carried out starting from graphite through the Hummers method [17] with a pre-oxidation step. Additionally, a centrifugation step was included at the end of the process. The GO obtained was reduced using 4 different methods: chemical, thermal, gamma radiation, and electron beam. Figure 1 shows the synthesis routes for all samples. Graphite, GO, and rGO obtained by all methods were characterized, and the nomenclatures are shown in Table 1.

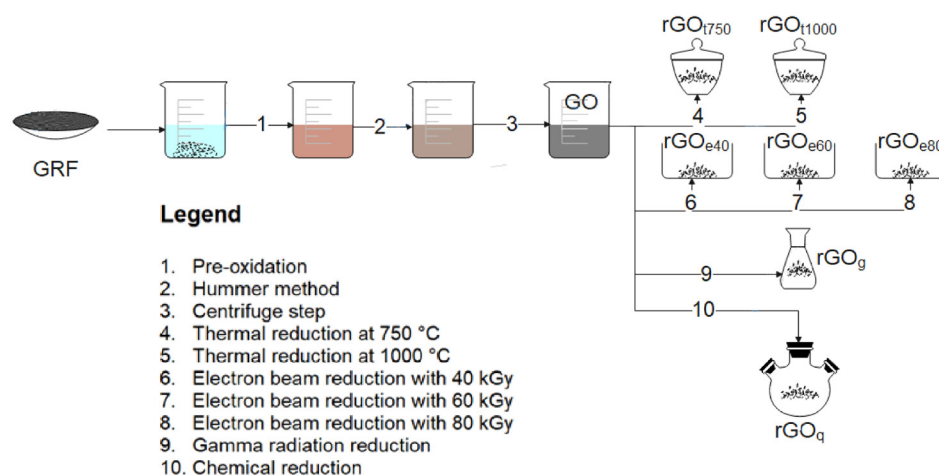


Figure 1. Schematic illustration of GO and rGO syntheses.

Table 1. Nomenclatures of different samples produced.

Nomenclature	Samples Description
GRF	Graphite
GO	Graphene oxide
rGOq	Reduced graphene oxide by chemical reduction
rGOt750	Reduced graphene oxide by thermal reduction at 750 °C
rGOt1000	Reduced graphene oxide by thermal reduction at 1000 °C
rGOe40	Reduced graphene oxide by electron beam reduction at 40 kGy
rGOe60	Reduced graphene oxide by electron beam reduction at 60 kGy
rGOe80	Reduced graphene oxide by electron beam reduction at 80 kGy
rGOg	Reduced graphene oxide by gamma radiation

2.1. Preparation of Graphene Oxide

Graphite (10 g) was pre-oxidized with sulfuric acid, potassium persulfate and diphosphorus pentoxide. The dispersion remained at 80 °C for 6 h under continuous stirring. After that, this dispersion was washed with distilled water and filtered until achieving a pH of around 7. Subsequently, the material pre-oxidized was dried in an oven at 60 °C for 24 h. Next, the pre-oxidized graphite was subjected to the modified Hummers' method: 460 mL of sulfuric acid and 5.0 g of sodium nitrate were added to the pre-oxidized graphite, stirring continuously, and keeping it in an ice bath (temperature around 5 °C) for 30 min. After that, 30.0 g of potassium permanganate was added slowly for 30 min, and keeping the reaction cooled for another 30 min. After this time, the dispersion was heated to 40 °C for a period of 2 h. Then, 920 mL of deionized water was added. The dispersion remained under stirring for another 15 min. After that, 50 mL of hydrogen peroxide solution was added to the dispersion and stirred for 30 min. Gradually the dispersion changed from dark greenish black to a yellow color, indicating a high level of oxidation. The dispersion was then filtered using a Büchner funnel in a vacuum system with 1 L of HCl. Then, the material retained in the funnel was dialyzed with deionized water for 4 days until neutral pH. Afterward, the material was subjected to an ultrasonication process for 1 h, using a probe of 19 mm and 70% of amplitude (Ultrathermostatic Quimis, 120 W, 40 kHz), followed by centrifugation at 2000 rpm for 15 min. A centrifugation process was applied to remove particles that were not completely oxidized.

2.2. Preparation of Reduced Graphene Oxide by Chemical Reduction

The dispersion containing 1 g of GO was subjected to ultrasound for 60 min, with an amplitude of 60% (Ultrathermostatic Quimis, 120 W, 40 kHz). After that, deionized water was added until the dispersion completed 1 L. Then, 6 g of sodium borohydride was added, followed by heating for 3 h at 120 °C. After heating, the dispersion was filtered with

deionized water, diluted in 4 L, and then filtered again [41]. The resulting dispersion was lyophilized.

2.3. Preparation of Reduced Graphene Oxide via Thermal Reduction

The thermal reduction was carried out by heating the lyophilized GO in an atmosphere of N₂ (flow of 0.12 m³/h) using an oven at 750 °C and 1000 °C. After reaching the temperature, the GO was kept at a constant temperature for 45 s [37].

2.4. Preparation of Reduced Graphene Oxide by Gamma Radiation Reduction

The GO dispersion was diluted in a solution of 50% (v/v) ethanol and deionized water. The dispersion was submitted to radiation in the cobalt-60 compact type multipurpose irradiator of the Radiation Technology Center (CETER) at IPEN (Instituto de Pesquisas Energéticas e Nucleares, São Paulo, Brazil). As the radiation hitting the sample's surface varies according to the distance to the radioactive source [52], the irradiation was performed in two stages, rotating the sample by 180° between stages. The total radiation dose was 80 kGy, applied at a dose rate of 7.8 kGy/h [42]. The resulting dispersion was lyophilized.

2.5. Preparation of Reduced Graphene Oxide by Electron Beam Reduction

The GO dispersion was diluted in a solution of 50% (v/v) ethanol and deionized water. The irradiation process was carried out in the JOB 188 electron beam accelerator (Dynamitron[®], Edgewood, NY, USA), a commercial equipment of the CETER—IPEN. To guarantee the complete radiation of the samples, the dispersion did not exceed 3 mm in thickness. The dose rate was 2.68 kGy/h, and the total radiation doses were 40, 60, and 80 kGy [47]. The resulting dispersion was lyophilized.

2.6. Characterization

Raman spectroscopy was performed on lyophilized samples. At least 3 spectra were obtained for each sample, using a Raman spectrometer, confocal Raman microscope Alpha300 R (WITec, Ulm, Germany), with a green wavelength of 532 nm and 45 mW. The calculation of the crystallite size of the samples was done by the equation described below [53,54]:

$$La \text{ (nm)} = 2.4 \cdot 10^{-10} \cdot \lambda_{laser}^4 \cdot \frac{I_G}{I_D}, \quad (1)$$

where I_G/I_D is the ratio between the intensities of the G and D bands. The λ_{laser} refers to the laser wavelength (nm).

Samples were also analyzed using Fourier transform infrared spectroscopy (FTIR), using a Nicolet iS10 (Thermo Scientific, Waltham, MA, USA), using the attenuated total reflectance (ATR) apparatus. X-ray diffractometry (XRD) analysis was performed in a Miniflex diffractometer (Rigaku, Cedar Park, TX, USA), with copper as the x-rays source ($\lambda = 1.5418 \text{ \AA}$), steps of 0.02°, and soaking time of 5 s. The interlayer spacing of GO and rGO was calculated using Bragg's equation [38]. A scanning electron microscope (SEM) was applied to analyze GO and rGO morphologies using a FEI Company field emission Inspect F50 instrument (Hillsboro, OR, USA). All samples were coated with gold for conduction purposes. Energy-dispersive spectrometry (EDS) was used to analyze the chemical composition of the graphene oxides and reduced graphene oxides. The reported results were an average of at least 10 measurements from different regions on the sample. Atomic force microscopy (AFM) was performed using the Bruker MultiMode 8 atomic force microscope (Billerica, MA, USA) on samples prepared on a mica surface.

3. Results

3.1. Raman Spectroscopy

Raman spectroscopy data and curves are shown in Table 2 and Figure 2. The Raman spectrum of the GRF (Figure 2a) shows the G band positioned at 1593 cm⁻¹, presenting an area 4.8 times larger than the D band, identified at 1366 cm⁻¹. The I_D/I_G ratio was

0.18, showing the higher intensity of the G band, as a result of regularity in the stacking of the graphitic structure, with a full width at half maximum (FWHM) of $\sim 23 \text{ cm}^{-1}$. This band corresponds to sp^2 carbon vibrations of the graphene layers. On the other hand, the D band, with an FWHM value of $\sim 50 \text{ cm}^{-1}$, indicates the presence of heteroatoms, point dislocations in the structure, and other defects [55,56]. The 2D band, the second highest intensity in the spectrum, is positioned at 2730 cm^{-1} , also due to the interactions between the stacked graphene layers [57]. The crystallite size (L_a) obtained was 104 nm.

Table 2. Data obtained from the Raman spectra of all reduced graphene oxides.

	D Band/FWHM (cm^{-1})	G Band/FWHM (cm^{-1})	2D Band (cm^{-1})	L_a (nm)	I_D/I_G
GRF	1366/49.9	1593/22.8	2730	104.0	0.18
GO	1370/207.6	1608/170.1	2668	18.3	1.05
rGOq	1341/99.8	1588/89.5	2679	15.9	1.21
rGOe80	1343/75.1	1572/71.8	2665	15.6	1.23
rGOe60	1343/81.5	1574/77.7	2679	16.9	1.14
rGOe40	1343/92.7	1578/82.5	2669	17.9	1.07
rGOg	1341/83.6	1576/74.5	2679	15.9	1.21
rGOt750	1344/193.9	1585/174.3	2657	19.3	1.00
rGOt1000	1344/170.6	1585/111.5	2647	18.7	1.03

GO Raman spectra can be shown in Figure 2b. Both D and G bands are also observed in the GO spectrum, with an I_D/I_G ratio of 1.05. This value refers to the presence of sp^3 hybridization regions, resulting in the prominent D band. Both bands are wider than the ones observed for graphite, indicating a decrease in the sp^2 domains. This broadening was confirmed using the FWHM values, which were 208 and 170 cm^{-1} , for the D and G bands, respectively. The L_a decreased from 104 to 18.3 nm, reflecting the lower content of graphitic domains (i.e., disruption of the graphitic stacking order) [55–57].

Figure 2c shows the Raman spectra of the rGO produced via thermal reduction. Despite both I_D/I_G ratios of rGOt750 and rGOt1000 being similar in comparison with the one for GO, the D and G bands were narrowed, as confirmed by the lower value of the FWHM for GO, indicating that rGOt750 and rGOt1000 have less oxygen-containing groups in their structures when compared to GOs [56]. L_a did not change significantly when compared to GO. The 2D bands are barely identifiable, positioned around 2660 cm^{-1} .

The Raman spectra of the GO reduced by electron beam (rGOe40, rGOe60, rGOe80) are shown in Figure 2d. The I_D/I_G ratio increased proportionally with the radiation dose: 1.07, 1.14, and 1.23 for rGOe40, rGOe60, and rGOe80, respectively. These results suggest an increase in the number of new domains, with a higher density of defects, such as grain boundaries and a higher number of edges present in the carbon backbone, due to the reduction process [56]. The FWHM of the D and G bands decreased with the increasing dose. This difference is probably due to the lower quantity of oxygen-containing groups in the graphene layers. Crystallite sizes decreased with the increase in the radiation dose level [47]. rGOe80 and rGOg presented similar Raman spectra, although the I_D/I_G ratio for rGOe80 resulted in a small increase (around 1.5%) in comparison to the one for rGOg. In addition, the lower FWHM in D and G bands suggests that e-beam radiation causes higher GO reduction than gamma rays [49]. rGOq (Figure 2e) showed the D (1341 cm^{-1}) and G (1588 cm^{-1}) bands with widths narrower than those of unreduced GO. The ratio of the intensities of the D and G bands, 1.21, was similar to the ones of rGOg and rGOe80 [56].

According to Saito et al. [58], the presence of disorder activates certain vibrational modes, which, in ordered structures, are inexpressive, such as the D and D' band modes and the D + D' combination mode. The authors reported the evolution of the 2D band and the D + D' band in monolayer graphene submitted to ion bombardment. The combined modes of D + D', at 2930 cm^{-1} , could only be observed at higher doses of ion bombardment. Similar results were also found when graphene was subjected to electron beam bombardment, as

presented by Childres et al. [59], which was also discussed by Selhorst and co-authors [60]. Therefore, the 2D and D + D' bands observed in the curves of rGOg and rGOe, Figure 2d,e, suggest that the radiation doses used in the present study introduced defects in the rGO structures.

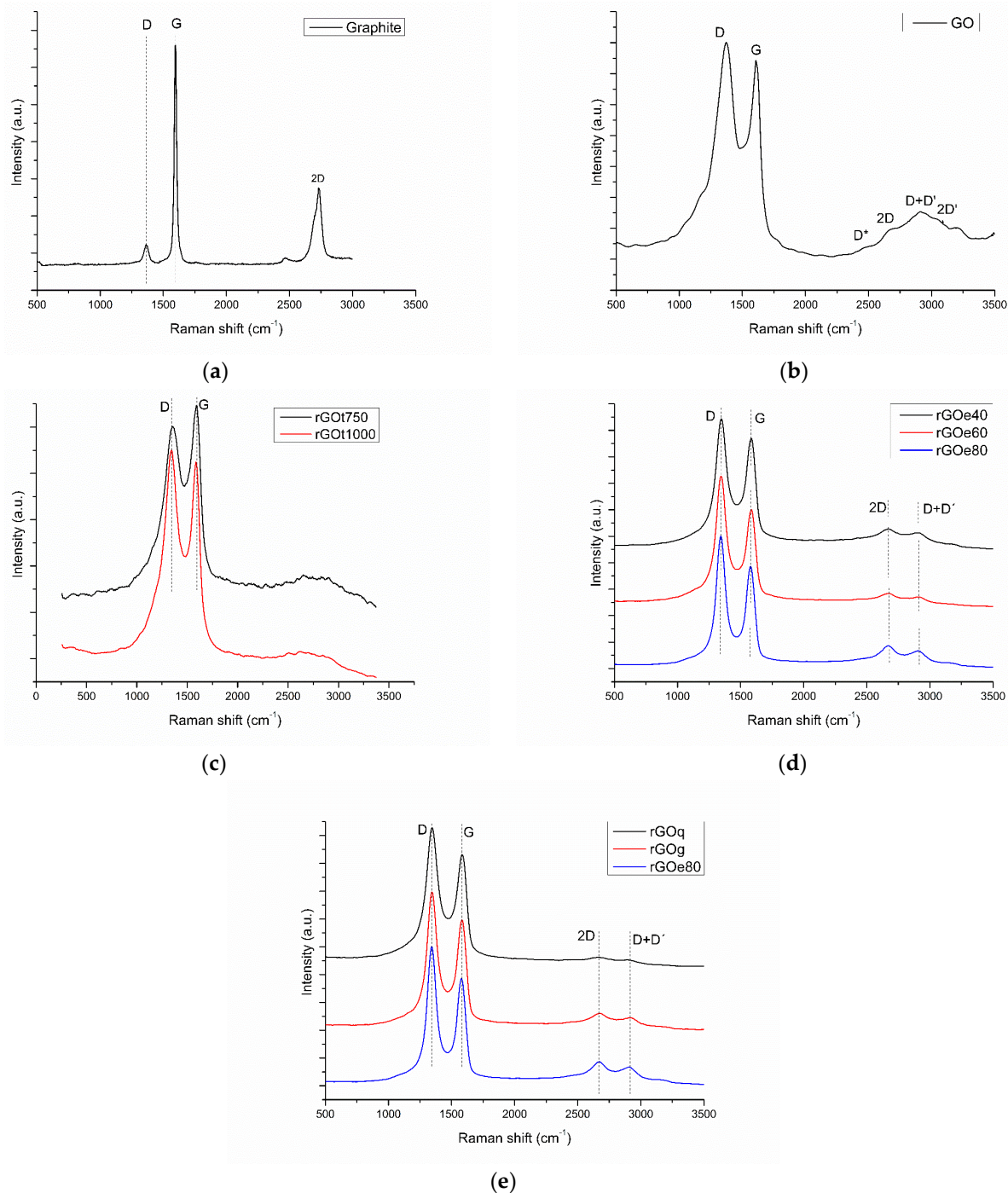


Figure 2. Raman spectra of: (a) GRF; (b) GO; (c) rGOt750 and rGOt1000; (d) rGOe40, rGOe60, and rGOe80; (e) rGOq, rGOg, and rGOe80.

To prove the reproducibility of the protocols proposed in this work, Figure S1 shows Raman spectra of the first and second production batches of GO and rGOs. All samples showed reproducibility in the curve profile and in the I_D/I_G ratio.

3.2. X-ray Diffraction (XRD)

The XRD curves for GRF, GO, and rGO are shown in Figure 3 and Table 3. Graphite exhibits very sharp diffraction peaks at $2\theta = 26.3^\circ$ and 54.6° , corresponding to an interplanar spacing of 3.4 Å and 1.7 Å, assigned to the (002) and (004) planes of the graphite's hexagonal structure, respectively. The GOs XRD pattern exhibits a peak at $2\theta \sim 10^\circ$, corresponding to an interplanar spacing of 8.7 Å, attributed to the (001) plane of GO [61]. The insertion of oxygen-containing functional groups during the oxidation process, such as epoxy and carbonyl groups, impacts the spacing increase between the layers [62]. Furthermore, these hydrophilic oxygen-containing functional groups absorb water molecules, thereby also contributing to the increase in the interlayer spacing. The absorbed water molecules in the basal plane galleries and structural defects cause the interplanar spacing to vary in the range of 6.1 Å, for dry GO, to 12 Å, for hydrated GO [63].

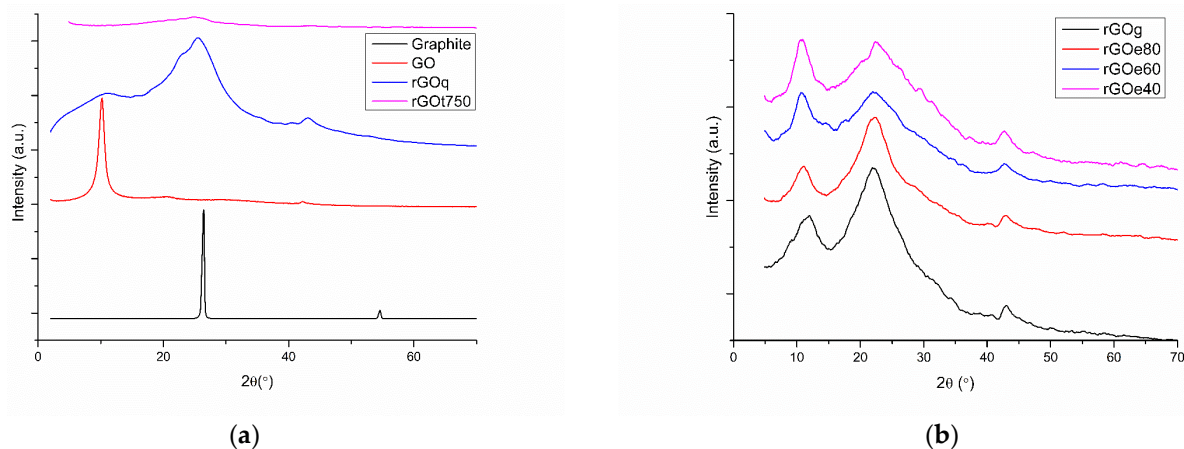


Figure 3. XRD patterns of (a) graphite, GO, rGOt750, rGOq; (b) rGOq, rGOe80, rGOe60, and rGOe40.

Table 3. The structural parameters of the GRF, GO, and rGO are determined using XRD technique: 2θ (diffraction angle), and d (interlayer space).

	2θ (°)	d (Å)
GRF	26.3	3.4
GO	42.3/10.1	2.1/8.7
rGOq	43.1/25.3/10.9	2.1/3.5/8.1
rGOg	43/22.2/11.3	2.1/4.0/7.8
rGOt750	43.8/24.7	2.1/3.6
rGOe80	42.8/22.2/11.1	2.1/4.0/7.9
rGOe60	42.7/22.1/10.7	2.1/4.0/8.2
rGOe40	42.7/22.6/10.5	2.1/3.9/8.4

The ordered crystal structure was partially restored when GO was reduced. This is verified by the reappearance of a wide diffraction peak, due to the irregular stacking of the graphene layers, from 22° to 25° , corresponding to an interplanar spacing around 4 Å, assigned to the plane (002) of rGO. In addition, the peaks around $2\theta = 42^\circ$ (for GO) and $2\theta = 44^\circ$ (for reduced GOs) are related to a short-range order within the layers of the stacked graphene, which are present in the semicrystalline, typical profile of the turbostratic graphite structure [64–66].

Furthermore, it also presents a peak around 10° for the reduced GOs, with the exception of the one thermally reduced, which may suggest that part of the GO was not completely reduced [67]. Conversely, the XRD curve of the thermally reduced material revealed a completely amorphous structure because of the lack of diffraction peaks. When comparing the curves of rGOe40, rGOe60, and rGOe80, it was observed that the peak intensities at around 22° increase as the dose rises, suggesting that the reduction was most effective for 80 kGy [47,49].

3.3. Fourier Transform Infrared Spectroscopy (FTIR)

FTIR spectra of GO and reduced GO samples can be seen in Figure 4. It is possible to identify the presence of oxygen-containing functional groups in the GO spectrum, indicating that groups were covalently bonded to the basal plane of the graphitic structure. An intense and broad band between 3700 and 3000 cm^{-1} is related to O-H stretching, which can be attributed to the hydroxyl and COOH groups present in the GO [63]. The band at approximately 1730 cm^{-1} corresponds to the carboxyl/carbonyl (C=O) stretching groups [61]. The band at around 1615 cm^{-1} is generated by the structural vibrations of the graphitic domains, being attributed to the C=C stretching of the aromatic rings. The band at 1170 cm^{-1} is associated with the C-O-C stretching, referring to the epoxy groups. The sharp band around 1045 cm^{-1} is attributed to O-H deformations, characteristic of C-OH groups [63,68,69]. The spectra of all reduced GO samples showed a decrease in band intensities related to the carbon–oxygen functional groups, in particular for the sample thermally reduced at 1000 °C [47].

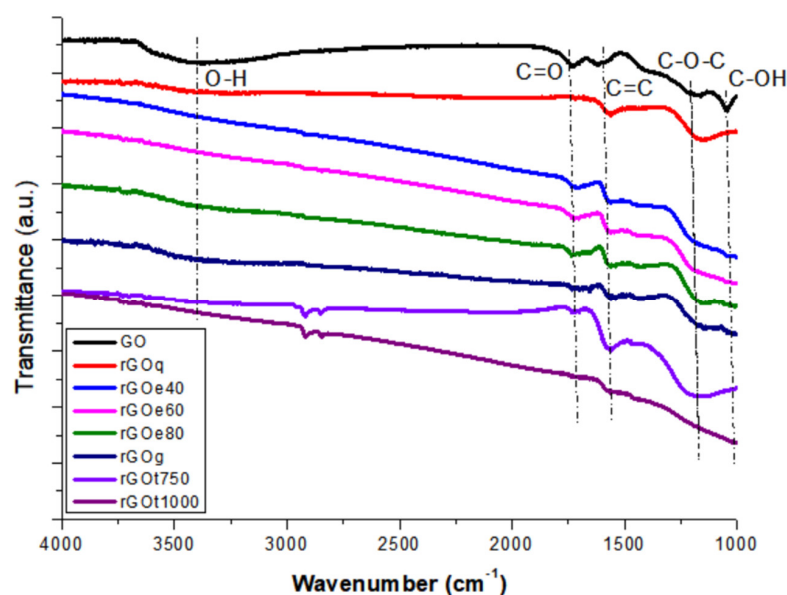


Figure 4. FTIR spectra of GO, rGOq, rGOe40, rGOe60, rGOe80, rGOg, rGOt750, and rGOt1000.

3.4. Energy-Dispersive Spectrometry (EDS)

EDS analysis (Table 4) was performed to compare the elemental compositions of the GO and rGO samples. The EDS results corroborate FTIR analysis, suggesting that all reduction methods contributed to the oxygen percentage decrease in rGO when compared to the ones for GO.

The C/O ratios ranged between 1.6 and 6.2. The following sequence represents the C/O values in ascending order: GO, rGOe40, rGOe60, rGOq, rGOt750, rGOg, rGOe80, and rGOt1000. The rGOe80 and rGOt1000 exhibited the lowest oxygen contents among all reduced GO. With regard to rGOq the presence of residual sodium was identified, most likely due to contamination caused by sodium borohydride, the reduction agent used in this process [63,70].

3.5. Scanning Electron Microscopy (SEM)

The morphological structure of GRF, GO and rGO were analyzed using scanning electron microscopy. The micrographs are shown in Figure 5. In general, graphite presented particles larger than 50 μm (Figure 5a). However, the images show that after the oxidation process, the size of the particles decreased (Figure 5b). The morphology of graphite shows compacts of platelets and flat particles with well-defined edges. On the other hand, the GO particles show a more open structure, with irregular curved edges and the presence of folded surfaces, due to the expansion of the interlayer spacings and the lower amount

of ordered stacked sheets caused by particle breaks and the attachment of the oxygen-containing functional groups [61]. After the reduction process (Figure 5c–i), the particles presented morphologies with greater roughness as a result of the defects generated in the structure of the basal plane via the removal of the oxygen-containing groups. The roughness was more evident for rGOe40, rGOe60, and rGOe80 (Figure 5d–f). Regarding the rGOt750 and rGOt1000 (Figure 5h–i), the particles presented much smaller sizes, around 10 μm . Nevertheless, for these thermally reduced GO, a re-stacking was not allowed, as observed by XRD patterns [61,63,71]. In addition, during the thermal reduction treatment, micro-explosions occur when the oxygen-containing groups are released, resulting in small and porous particles and a high loss of material (above 90%), comprising the disadvantages of such a method.

Table 4. Semi-quantitative elemental composition, by EDS, of GO and rGO, and the corresponding C/O ratio.

	C (%)	O (%)	Na (%)	C/O
GO	60.8	39.2	0	1.6
rGOq	70.3	23.7	6.0	3.0
rGOe80	84.4	15.6	0	5.4
rGOe60	74.4	25.6	0	2.9
rGOe40	71.7	28.3	0	2.5
rGOg	80.3	19.7	0	4.1
rGOt750	79.1	20.9	0	3.8
rGOt1000	86.1	13.9	0	6.2

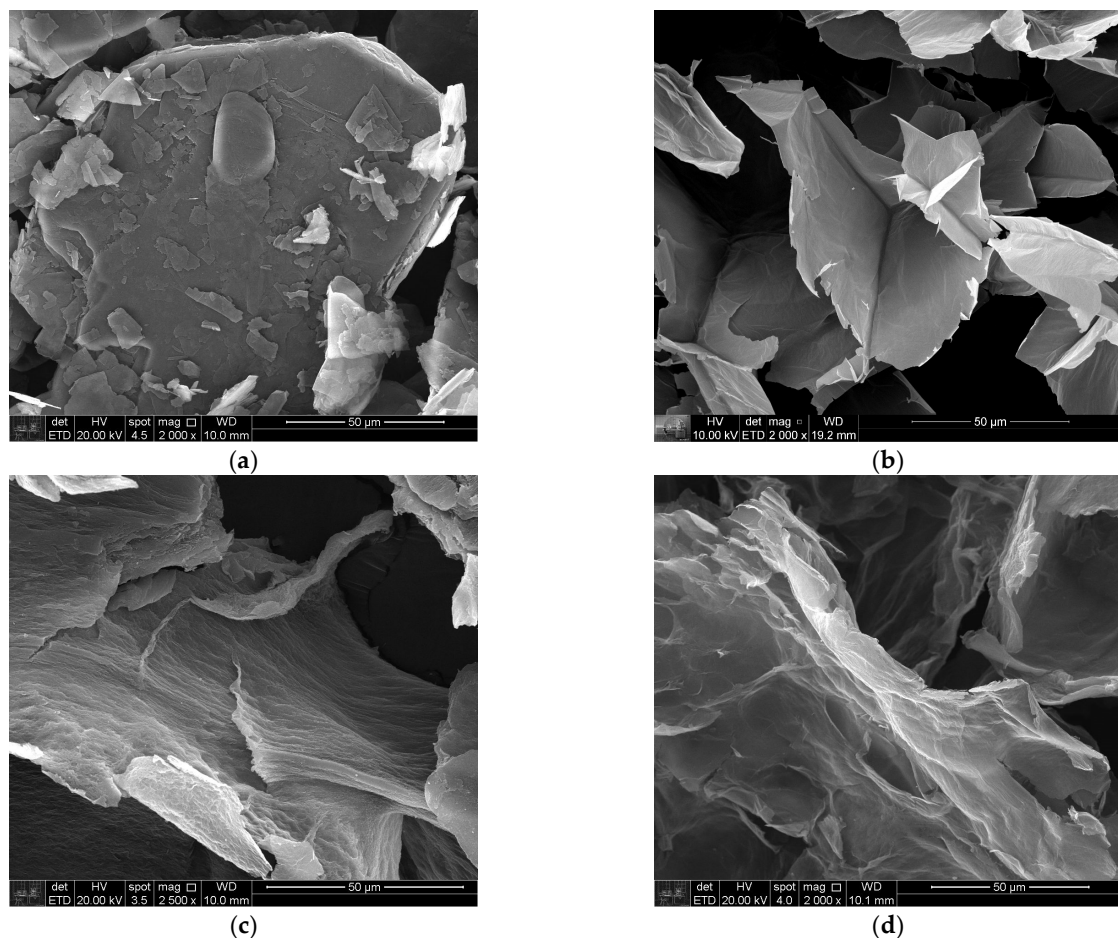


Figure 5. Cont.

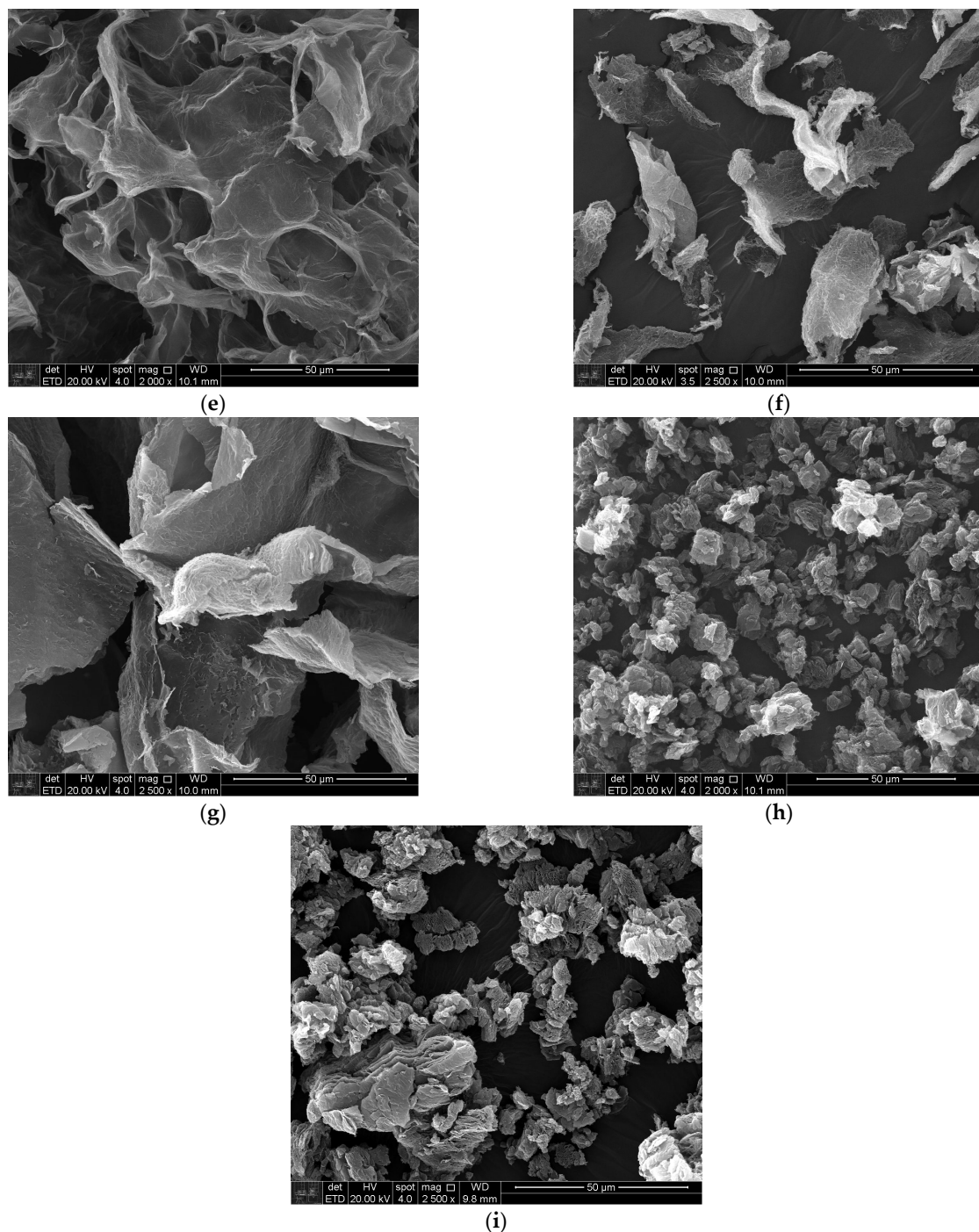


Figure 5. SEM micrographs: (a) GRF; (b) GO; (c) GOq; (d) GOe40; (e) GOe60; (f) GOe80; (g) GOg; (h) GOt750; (i) GOt1000.

3.6. Atomic Force Microscopy (AFM)

AFM analysis was performed to determine the thickness of isolated GO and rGO flakes. Figure 6 shows both the image and the thickness profile (three directions scan per image) of GO, rGOq, rGOe80, and rGOg flakes. It can be seen in Figure 6a a GO particle with approximately 3 μm of width and thickness varying from 1 to 1.5 nm. This suggests that the oxidized graphite was properly exfoliated to obtain thin flakes of graphene oxide [12,44]. Figure 6b–d show the thicknesses of reduced GOs: around 2 nm for rGOq, around 2 nm for rGOe80, and around 8 nm for rGOg. When compared to the GO flake, the thicknesses of the reduced GO particles increased. This means that the oxygen-containing groups were

removed, which makes the layers come close together, and a re-stacking of the layers took place. Both rGOq and rGOe80 flakes can be classified as multi-layer graphene, whereas rGOg can be classified as graphite nanoflakes or nanoplates [7].

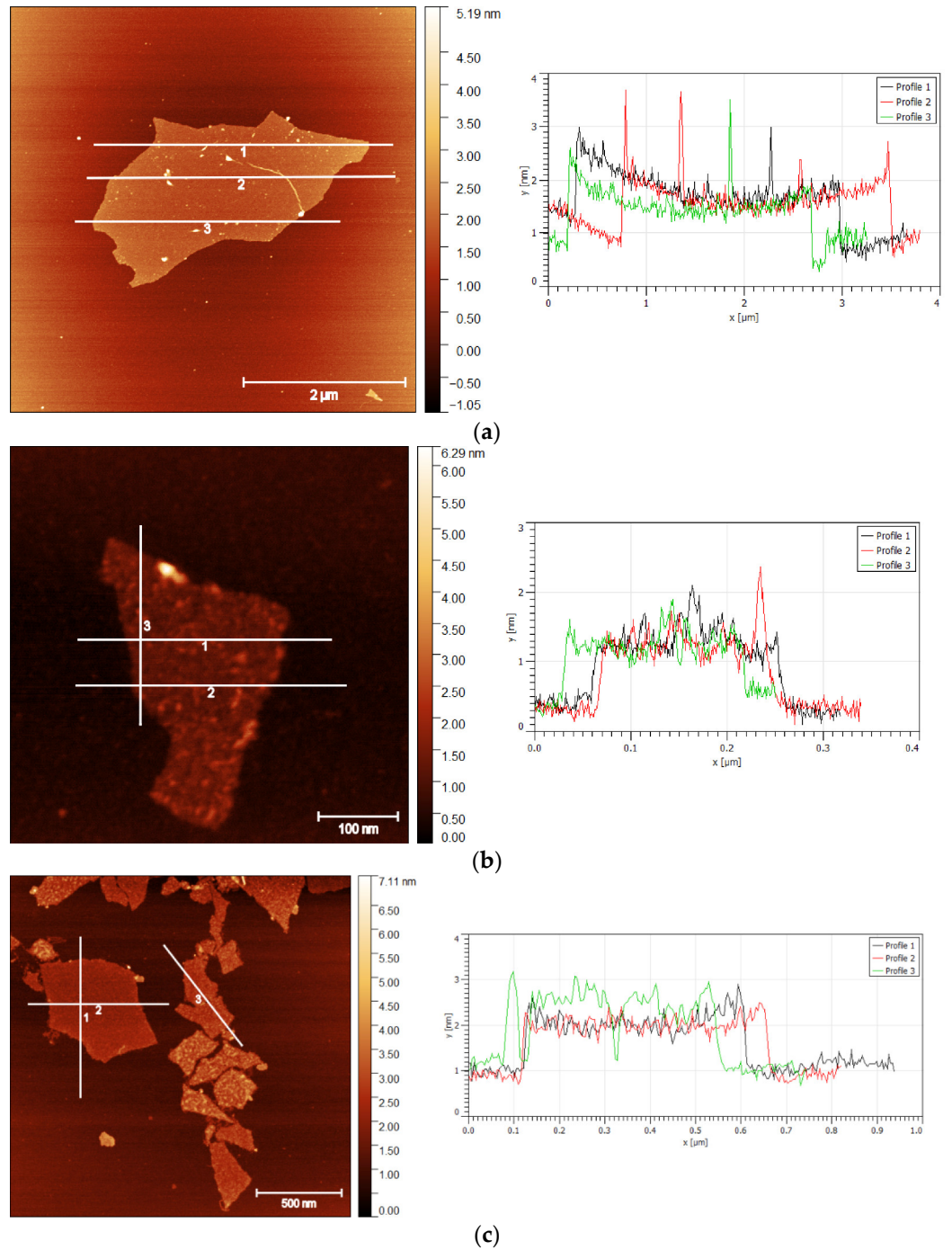


Figure 6. Cont.

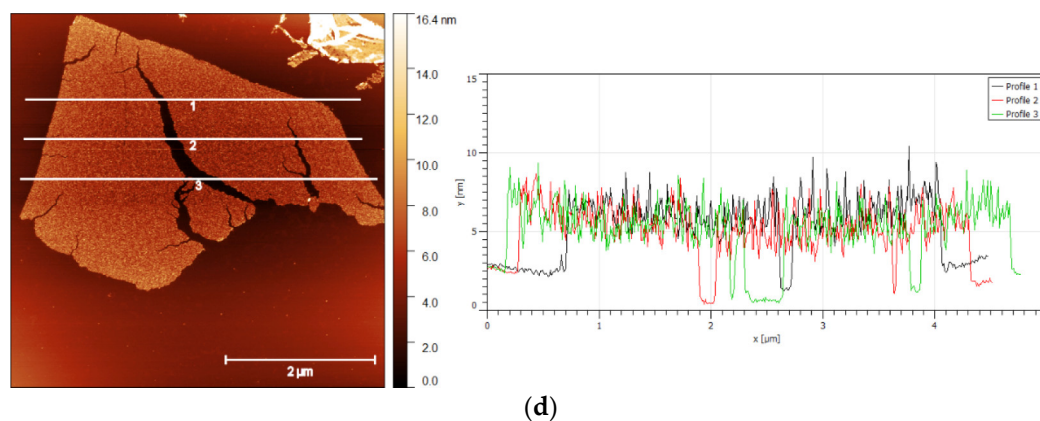


Figure 6. AFM of (a) GO; (b) rGOq; (c) rGO; (d) rGOg. Three thickness profile direction scans per image (1–3).

4. Conclusions

The protocols for GO production, starting from graphite, were adapted from the original method described by Hummers [17] to increase production scale and ensure graphite oxidation. The addition of pre-oxidation and centrifugation processes rendered a higher amount of GO per batch.

It was possible to observe through the Raman spectra of the GO that the typical D band was prominent, and both D and G bands are wider than the ones observed for graphite, which is caused by the insertion of the large number of oxygen-containing groups and other defects in the graphene layers. The combined analyses of the XRD patterns and FTIR and EDS spectra confirmed the graphite oxidation and the obtention of GO particles. In addition, the C/O atomic ratio was 1.6. According to Bianco et al. [7], GO C/O ratios must be less than 3.0 and typically closer to 2.0.

When comparing the GO reduction techniques, the traditional thermal and chemical reduction, as well as the more recent ionizing radiation reduction using gamma rays and e-beam, dramatic differences in the efficiency, and the GO particle characteristics, were observed.

It was found that, as extensively reported in the literature, thermal reduction is an effective reduction method. The rGOt1000 presented the lowest oxygen content, with a C/O ratio of 6.2. Furthermore, the particles presented the smallest sizes, and the XRD curves revealed a complete lack of diffraction peaks, revealing that the re-stacking was not allowed. However, the disadvantage of this method is the high loss of material during the thermal reduction (above 90%) caused by micro-explosions during the release of the oxygen-containing functional groups.

The results for rGOq showed a satisfactory reduction, as evidenced by the decrease in the absorption band intensities corresponding to the oxygen-containing functional groups in the FTIR spectrum and an intermediate oxygen content (EDS) when compared to the other reduction methods. It is important to highlight that the final product contained sodium as a contaminant (EDS), and the procedure may involve the use of hazardous compounds, such as hydrazine monohydrate ($\text{N}_2\text{H}_4 \cdot \text{H}_2\text{O}$) and sodium borohydride (NaBH_4).

Regarding the radiation reduction methods, both gamma rays and e-beam were effective in obtaining rGO. Particularly, when comparing the two techniques for the same radiation dose, that is, rGOe80 and rGOg, the Raman spectra suggested that the e-beam technique caused a higher GO reduction than the gamma ray technique, as corroborated by the C/O atomic ratio from the EDS analysis, which resulted in 5.4 and 4.1, for rGOe80 and rGOg, respectively.

Finally, comparing the effects of different e-beam radiation doses, 40, 60, and 80 kGy, the Raman spectra and EDS chemical analysis showed that the I_D/I_G ratios and C/O atomic ratios increased with the radiation dose, whereas the interplanar spacing decreased

when the radiation dose increased. In other words, the reduction power increased with the radiation dose.

Furthermore, both radiation methods allow for easier control of the reduction degree when compared to the previous methods by adjusting the reduction radiation dose. However, it should be pointed out that both methods involve radiation production, which limits access to proper facilities and require the inherent care related to the use of high-energy radiation.

Supplementary Materials: The following supporting information can be downloaded at: <https://www.mdpi.com/article/10.3390/c9030073/s1>, Figure S1: Raman spectra of the first and second production batches of GO and rGOs: (a) GO; (b) rGO_q, (c) rGOe40, (d), rGOe60, (e) rGOe80, (f) rGO_g, (g) rGOt750, and (h) rGOt1000.

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